

TOPIC.

# GENERAL PROPERTIES OF SEMICONDUCTORS



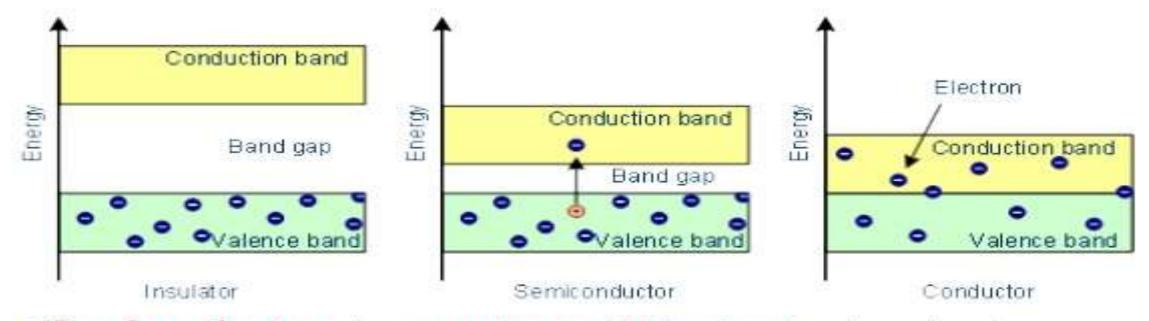
- In any material, there are 2 energy band:
- 1. Valence band: the outermost shell that determines the conductivity
- 2. Conduction band: the band outside the valence shell.

The 2 bands are separated by one energy gap called – forbidden gap.

- The valence band contains with electrons.
- The electrons can move to the conduction band if it have enough energy (eg: light or heat).
- When the electron absorbs enough energy to jump from valence band to the conduction band, the electron is said to be in excited state.

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 The concept of energy bands is particularly important in classifying materials as conductors, semiconductors, and insulators.



- <u>Semiconductor</u>: has a smaller forbidden band and requires less energy to move an electron from the valence band to the conduction band.
- Therefore, for a certain amount of applied voltage, more current will flow in the semiconductor than in the insulator.

#### semiconducting elements:

- low electrical conductivity at room temperature
- Electrical conductivity increases with temp.
- Gap between valence and conduction band is intermediate in size.
- Semiconducting elements form the basis of solid state electronic devices.
- Metalloids (such as silicon or germanium) are semiconducting elements whose electrical conductivity increases as temperature increases.
- A striking property of these elements is that their conductivities increase markedly when they are doped with small quantities of other elements.

- Made from materials that have four valence electrons in their outer orbitals.
- Germanium and silicon are the most common.
- Silicon is preferred due to its ability to withstand heat.
- A pure semiconductor material such as silicon or germanium has no special properties and will make a poor conductive material.



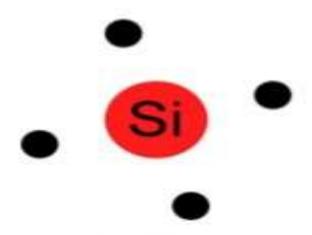
- When silicon is doped with phosphorus, it becomes an n-type semiconductor, in which electrical current is carried by negatively charged electrons.
- When silicon is doped with boron, it becomes a p-type semiconductor, in which an electrical current is carried by positively charged holes.
- Joining a p-type semiconductor to an n-type semiconductor produces a p-n junction, which can function as a rectifier.
- A rectifier is a device that allows current to flow in one direction, but not the other.

### : Types of Semiconductor

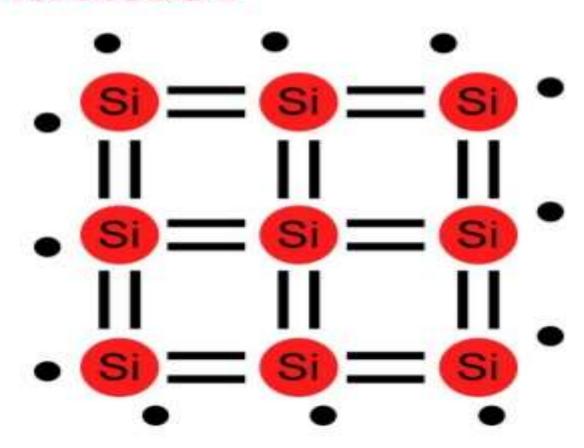
- Semiconductors are mainly classified into two categories:
  - i. Intrinsic
  - ii. Extrinsic
  - i. Intrinsic: chemically very pure and possesses poor conductivity.
    - It has equal numbers of negative carriers (electrons) and positive carriers (holes).
    - Impurities do not affect its electrical behavior.

#### Intrinsic Semiconductor

Silicon has 4 outer shell valence electrons



Forms into a lattice structure to share electrons



The pure semiconductor material without impurities atoms. example: Silicon and Germanium



#### Extrinsic semiconductor:

- improved intrinsic semiconductor with a small amount of impurities added by a process, known as doping process, which alters the electrical properties of the semiconductor and improves its conductivity.
- Introducing impurities into the semiconductor materials (doping process) can control their conductivity.



- Adding impurities atom into intrinsic semiconductor = extrinsic semiconductor.
- The process of adding specific types of atoms to a semiconductor to favorably alter electric characteristics – **Doping**
- 2 types of extrinsic (impure) semiconductor;
  - N-type
  - P-type



When an impurity increases the number of free electrons, the doped semiconductor is negative or n-type.

An impurity that reduces the number of free electrons, causing more holes, creates a positive or p-type semiconductor.



## Doping

- Doping : Adding impurities to the silicon crystal lattice to increase the number of carriers.
- Add a small number of atoms to increase either the number of electrons or holes.

